L Number	Hits	Search Text	DB	Time stamp	
1	2	6060714.pn.	USPAT;	2004/03/13	
		•	US-PGPUB;	15:49	
			EPO; JPO;		
			DERWENT		
2	. 0	6060714.pn. and (data adj line)	USPAT;	2004/03/13	
			US-PGPUB;	15:49	
			EPO; JPO;		
	_		DERWENT	0004/00/10	
3	0	6060714.pn. and (common adj line)	USPAT;	2004/03/13	
			US-PGPUB;	15:50	
			EPO; JPO;		
			DERWENT	2004/02/17	
-	0		USPAT;	12:10	
		(planarization adj layer) and (conformal	US-PGPUB; EPO; JPO;	12.10	
		adj passvation adj layer)	DERWENT		
	0	capacitor and transistor and	USPAT;	2003/12/23	
-	"	(planarization adj layer) and (conformal	US-PGPUB;	15:55	
		adj passivation adj layer)	EPO; JPO;	15.55	
		adj passivacion adj layer,	DERWENT		
	1	capacitor and transistor and	USPAT;	2003/12/23	
_		(planarization adj layer) and (conformal	US-PGPUB;	15:55	
		with (passivation adj layer))	EPO; JPO;	13.33	
		With (passivation ad) layer//	DERWENT		-
_	1	capacitor and transistor and	USPAT;	2003/12/23	
_	ļ -	(planarization adj layer) and (conformal	US-PGPUB;	16:11	
		same (passivation adj layer))	EPO; JPO;		
		Same (passivacion ad) rajer//	DERWENT		
_	1	capacitor and transistor and	USPAT;	2003/12/23	
	1	(planarization adj layer) and imager and	US-PGPUB;	16:12	
	1	conformal	EPO; JPO;		
		00111 02111012	DERWENT		
_	12	capacitor and transistor and	USPAT;	2003/12/23	
		(planarization adj layer) and imager	US-PGPUB;	16:24	
		(,F====================================	EPO; JPO;		
			DERWENT		
_	940	capacitor and transistor and imager	USPAT;	2003/12/23	
		-	US-PGPUB;	16:24	
			EPO; JPO;		
			DERWENT		
_	225	(storage adj capacitor) and transistor	USPAT;	2003/12/23	
		and imager	US-PGPUB;	16:25	
			EPO; JPO;		
			DERWENT		
_	0	1	USPAT;	2004/02/17	
		and (storage adj capacitor) and	US-PGPUB;	12:19	
		transistor and imager	EPO; JPO;		
			DERWENT	0004/00/17	
-	0	1 = : :	USPAT;	2004/02/17	
		capacitor) and transistor and imager	US-PGPUB;	12:23	
	•		EPO; JPO;		
	_		DERWENT	2002/12/24	
-	5	1 , , , , , , , , , , , ,	USPAT;	2003/12/24	
		and (storage adj capacitor) and	US-PGPUB;	11:55	
		transistor and imager	EPO; JPO;		
	-	438/240,155,200,239,256,279,393,394,395,39	DERWENT	00 0-0-3 (-1 2 / 2 /	
-	5		US-PGPUB;	11:57	
	1	and (storage adj capacitor) and	EPO; JPO;	11.57	
		transistor and imager	DERWENT		
_	7	438/240,155,200,239,256,279,393,394,395,39		92 0-0-7/412/24	
_	1 '	and (capacitor) and transistor and imager		11:57	
		and (capacitor) and cransistor and imager	EPO; JPO;	11.01	
			DERWENT		
_	8	257/295,296,297,298,299,300,301,302,303,30		72.000B/330/924310 311	312
_	°	and capacitor and transistor and imager	US-PGPUB;	12:42	, 512.
		and Sapacitor and clansistor and imager	EPO; JPO;		
			DERWENT		
	1	<u> </u>			L

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* 👟				
-	0		USPAT;	2004/02/17
		and transistor and imager	US-PGPUB;	12:21
			EPO; JPO;	
		050/070 00 500 014 11	DERWENT	2002/12/24
-	١	250/370.09,580,214.1,ccls. and capacitor and transistor	USPAT; US-PGPUB;	2003/12/24 12:45
		and transistor	EPO; JPO;	12:45
			DERWENT	
_	52	250/370.09,580,214.1.ccls. and capacitor	USPAT;	2003/12/24
	""	and transistor and imager	US-PGPUB;	12:46
		,	EPO; JPO;	
			DERWENT	
-	1	250/370.09,580,214.1.ccls. and capacitor	USPAT;	2003/12/24
		and transistor and imager and conformal	US-PGPUB;	12:46
			EPO; JPO;	
			DERWENT	
-	16	250/370.09,580,214.1.ccls. and capacitor	USPAT;	2003/12/24
		and transistor and imager and passivation	US-PGPUB;	12:54
			EPO; JPO; DERWENT	
	1	250/370.09,580,214.1.ccls. and capacitor	USPAT;	2003/12/24
-		and transistor and imager and passivation	US-PGPUB;	12:54
		and (conformal same passivation)	EPO; JPO;	12.31
		and (conformal same passivacion)	DERWENT	
_	l 0	250/370.09,580,214.1.ccls. and capacitor	USPAT;	2003/12/24
	Ĭ	and transistor and imager and passivation	US-PGPUB;	12:54
		and (conformal same passivation) and	EPO; JPO;	
		source and drain	DERWENT	
! -	15		USPAT;	2003/12/24
		and transistor and imager and passivation	US-PGPUB;	12:55
;		and source and drain	EPO; JPO;	
			DERWENT	
-	. 0		USPAT;	2003/12/24
		adj capacitor) and transistor and imager	US-PGPUB;	12:56
		and passivation and source and drain and	EPO; JPO;	İ
		planarization	DERWENT	
-	10	250/370.09,580,214.1.ccls. and (storage	USPAT;	2003/12/24
		adj capacitor) and transistor and imager	US-PGPUB;	14:40
		and passivation and source and drain	EPO; JPO;	
			DERWENT USPAT;	2003/12/24
-	0	TW-540128-\$.did.	US-PGPUB;	14:45
			EPO; JPO;	14.45
			DERWENT	
1_	0	TW-0000540128-\$.did.	USPAT;	2003/12/24
		" 0000310120	US-PGPUB;	14:45
1			EPO; JPO;	
1	}		DERWENT	
-	0	TW-5401280000-\$.did.	USPAT;	2003/12/24
1			US-PGPUB;	14:45
1	1		EPO; JPO;	
	1		DERWENT	
-	2	6362041.PN.	USPAT;	2003/12/24
1	1		US-PGPUB;	14:48
	1		EPO; JPO;	
1	_	00000111740 79	DERWENT	2002/12/24
-	2	20030111740.PN.	USPAT;	2003/12/24 14:50
1	1		US-PGPUB; EPO; JPO;	14:20
	ĺ		DERWENT	
I _	2	6340638.PN.	USPAT;	2003/12/24
1 -	2	0040000.EM.	US-PGPUB;	15:20
			EPO; JPO;	
1	[DERWENT	
-	2	6184121.PN.	USPAT;	2003/12/24
			US-PGPUB;	14:53
			EPO; JPO;	
1			DERWENT	
-	2	5198694.PN.	USPAT;	2003/12/24
	_		US-PGPUB;	15:07
			EPO; JPO;	
1	1		DERWENT	1

1 No.				
-	0	200340107687.PN.	USPAT;	2003/12/24
			US-PGPUB;	15:07
			EPO; JPO;	
			DERWENT	
-	2	20030107687.PN.	USPAT;	2003/12/24
			US-PGPUB;	15:08
			EPO; JPO;	
			DERWENT	2222/12/2/
-	0	KR-220058794-\$.did.	USPAT;	2003/12/24
			US-PGPUB;	15:09
			EPO; JPO;	
		700 220250704 ¢ did	DERWENT USPAT;	2003/12/24
-	' '	KR-220258794-\$.did.	US-PGPUB;	15:10
			EPO; JPO;	15:10
			DERWENT	
l _	ا م	KR-200258794-\$.did.	USPAT;	2003/12/24
			US-PGPUB;	15:10
			EPO; JPO;	
			DERWENT	
l	1	KR-2002058794-\$.did.	USPAT;	2003/12/24
1		·	US-PGPUB;	15:12
			EPO; JPO;	
			DERWENT	
-	1	KR-2002004267-\$.did.	USPAT;	2003/12/24
			US-PGPUB;	15:12
			EPO; JPO;	
			DERWENT	
-	2	6051876.PN.	USPAT;	2003/12/24
			US-PGPUB;	15:23
			EPO; JPO;	
		5.00.700 PV	DERWENT	2003/12/24
-	2	5688709.PN.	USPAT; US-PGPUB;	15:47
			EPO; JPO;	13.47
			DERWENT	
_	0	5198694.PN. and (data adj line)	USPAT;	2003/12/24
_		3150054.1W. and (data da) 11Me/	US-PGPUB;	15:49
			EPO; JPO;	
	ļ		DERWENT	
_	l o	5198694.PN. and (gate adj line)	USPAT;	2003/12/24
		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	US-PGPUB;	15:49
			EPO; JPO;	
			DERWENT	
-	0	6060714.pn. and (data adj line)	USPAT;	2004/02/17
				12:12
			EPO; JPO;	
			DERWENT	0004/00/17
-	2	6060714.pn.	USPAT;	2004/02/17
			US-PGPUB;	12:13
			EPO; JPO; DERWENT	
_	0	6060714.pn. and (drain same data)	USPAT;	2004/02/17
1-	"	oooo/14.pm. and (drain same data)	US-PGPUB;	12:13
			EPO; JPO;	
			DERWENT	
_	0		USPAT;	2004/02/17
		393,399.ccls. and (storage adj capacitor)	US-PGPUB;	12:20
		and transistor and imager	EPO; JPO;	
			DERWENT	
-	0		USPAT;	2004/02/17
		393,399.ccls. and (storage adj capacitor)	US-PGPUB;	12:20
		and transistor	EPO; JPO;	
			DERWENT	
-	0		USPAT;	2004/02/17
	1	and transistor	US-PGPUB;	12:32
			EPO; JPO;	
		057/005 006 007 000 000 000 001 000 000	DERWENT	72 0000 (000 01 78 1 0 2 3 1 1 2 3 2 3 3 1
-	4434			
		and (capacitor) and transistor	US-PGPUB; EPO; JPO;	12:28
			DERWENT	
L	L	<u> </u>	221111111	

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,					
_	14				2,31
		and (capacitor) and transistor and x-ray	US-PGPUB;	12:29	
		and detector	EPO; JPO;		
	ا _د	257/295,296,297,298,299,300,301,302,303,30	DERWENT	77 09009/090017910 311 313	21
-	4	and (capacitor) and transistor and (x-ray	US-PGPUB;	12:29	-,51
		same detector)	EPO; JPO;	12.23	
		bame accessor,	DERWENT		
_	0	250/59,370.09,580,214.1,ccls. and	USPAT;	2004/02/17	
		capacitor and transistor	US-PGPUB;	12:33	
			EPO; JPO;		
			DERWENT		
-	0	250/59,370.09,580,214.1,ccls. and imager	USPAT;	2004/02/17	
			US-PGPUB; EPO; JPO;	12:34	
			DERWENT		
l _	150	250/59,370.09,580,214.1.ccls. and imager	USPAT;	2004/02/17	
	130	200,05,5,0.05,000,211.1.0015. and 1	US-PGPUB;	12:34	
	1		EPO; JPO;		
			DERWENT		
-	25		USPAT;	2004/02/17	
		and (storage adj capacitor) and	US-PGPUB;	12:47	
		transistor	EPO; JPO;		
		050/50 270 00 500 014 1 ==3 1 4==-	DERWENT	2004/02/17	
-	25		USPAT; US-PGPUB;	12:35	
		and (storage adj capacitor) and transistor and imager	EPO; JPO;	12:33	
		Classistor and imager	DERWENT		
	25	250/59,370.09,580,214.1.ccls. and imager	USPAT;	2004/02/17	
		and (storage adj capacitor) and	US-PGPUB;	12:40	
		transistor and imager and @ad<20020712	EPO; JPO;		
		-	DERWENT		
-	0	= ,	USPAT;	2004/02/17	
		and (storage adj capacitor) and	US-PGPUB;	12:42	
		transistor and imager and @ad<20020712	EPO; JPO;		
	,	and planarazation	DERWENT USPAT;	2004/02/17	
-	2	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and	US-PGPUB;	12:42	
		transistor and imager and @ad<20020712	EPO; JPO;	12.12	
		and planarization	DERWENT		
_	2		USPAT;	2004/02/17	
		and (storage adj capacitor) and	US-PGPUB;	12:44	
		transistor and imager and @ad<20020712	EPO; JPO;		
	_	and planarization	DERWENT	0004/00/17	
-	1	250/59,370.09,580,214.1.ccls. and imager	USPAT;	2004/02/17	
		and (storage adj capacitor) and transistor and imager and @ad<20020712	US-PGPUB; EPO; JPO;	12:47	
		and conformal	DERWENT		
_	20		USPAT;	2004/02/17	
		and (storage adj capacitor) and	US-PGPUB;	12:47	
	1	transistor and imager and @ad<20020712	EPO; JPO;		
	1	and data	DERWENT		
-	10	250/59,370.09,580,214.1.ccls. and imager	USPAT;	2004/02/17	
1		and (storage adj capacitor) and	US-PGPUB;	12:48	
	1	transistor and (data adj line)	EPO; JPO;		
I_	2	250/59,370.09,580,214.1.ccls. and imager	DERWENT USPAT;	2004/02/17	
-	3	and (storage adj capacitor) and	US-PGPUB;	12:49	
1		transistor and (data adj line) and (gate	EPO; JPO;	· · · ·	
	1	adj line)	DERWENT		
-	0	10367756.pn.	USPAT;	2004/02/17	
			US-PGPUB;	15:44	
			EPO; JPO;		
			DERWENT	1 2004 /02 /22	
-	2	6020590.pn.	USPAT;	2004/02/19	
			US-PGPUB;	11:58	
			EPO; JPO; DERWENT		
1_	2	6060714.pn.	USPAT;	2004/02/19	
	1		US-PGPUB;	11:59	
			EPO; JPO;		
	l		DERWENT		

-	2	6124606.pn.	USPAT;	2004/02/19
		-	US-PGPUB;	11:59
			EPO; JPO;	
			DERWENT	